

**PHOTO COUPLER
INDUSTRIAL USE**

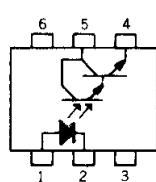
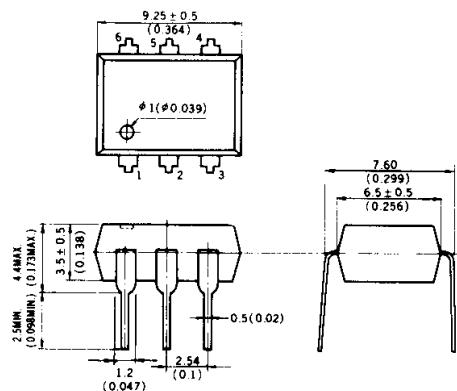
— NEPOC SERIES —

DESCRIPTION

The PS2002B is an optically coupled isolator containing a GaAsP light emitting diode and an NPN silicon darlington-connected phototransistor.

PACKAGE DIMENSIONS

in millimeters (inches)



(Top view)

1. Anode
2. Cathode
3. NC
4. Emitter
5. Collector
6. NC

FEATURES

- High Voltage Isolation 2500V_{DC} MIN.
- High Transfer Ratio 100% MIN.
- Economical, Compact, Plastic Dual In-Line Package

APPLICATIONS

- ECR
- Automat
- Replacement of pulse transformer.
- Other replacement of mechanical relay and reed relays.

ABSOLUTE MAXIMUM RATINGS (Ta = 25°C)

Diode

Reverse Voltage	V _R	7.0	V
Forward Current	I _F	50	mA
Power Dissipation	P _D	100	mW

Transistor

Collector to Emitter Voltage	V _{CEO}	40	V
Collector Current	I _C	50	mA
Power Dissipation	P _C	100	mW
Isolation Voltage* 1	BV	2500	V _{DC}
Storage Temperature	T _{stg}	-55 to +125	°C
Operating Temperature	T _{opt}	-55 to +100	°C

ELECTRICAL CHARACTERISTICS ($T_a = 25^\circ\text{C}$)

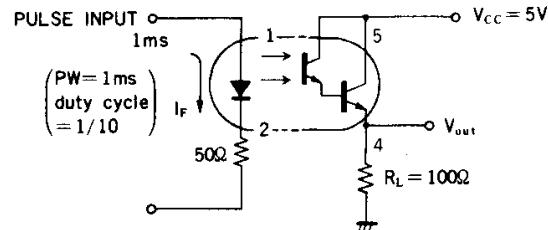
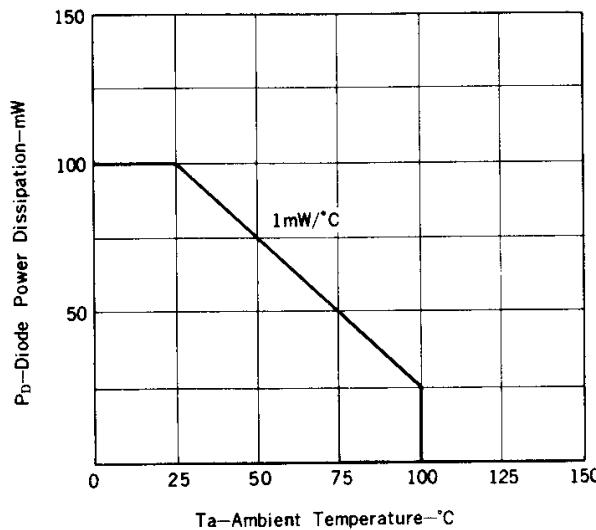
CHARACTERISTIC		SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Diode	Forward Voltage	V_F			1.9	V	$I_F = 5.0 \text{ mA}$
	Reverse Current	I_R			2.0	μA	$V_R = 4.0 \text{ V}$
	Junction Capacitance	C		100		pF	$V = 0, f = 1.0 \text{ MHz}$
Transistor	Collector to Emitter Dark Current	I_{CEO}			400	nA	$V_{CE} = 10 \text{ V}, I_F = 0$
	DC Current Gain	h_{FE}		5000			$I_C = 4.0 \text{ mA}, V_{CE} = 2.0 \text{ V}$
Coupled	Current Transfer Ratio	$CTR(I_C/I_F)$	100			%	$I_F = 5.0 \text{ mA}, V_{CE} = 2.0 \text{ V}$
	Collector Saturation Voltage	$V_{CE}(\text{sat})$			1.2	V	$I_F = 5.0 \text{ mA}, I_C = 2.0 \text{ mA}$
	Isolation Resistance	R_{1-2}	10^{11}			Ω	$V_{in-out} = 1.0 \text{ kV}$
	Isolation Capacitance	C_{1-2}		0.8		pF	$V = 0, f = 1.0 \text{ MHz}$
	Rise Time	t_r		100		μs	$V_{CC} = 5.0 \text{ V}, I_F = 10 \text{ mA}, R_L = 100 \Omega * 2$
	Fall Time	t_f		120		μs	$V_{CC} = 5.0 \text{ V}, I_F = 10 \text{ mA}, R_L = 100 \Omega * 2$

* 1 Measuring Condition

DC or AC voltage for 1 minute at $T_a = 25^\circ\text{C}$,
RH = 60%

Between input (pin No. 1, 2 and No. 3 Common)
and output (pin No. 4, 5 and No. 6 Common)

* 2 Test Circuit for Switching Time

TYPICAL CHARACTERISTICS ($T_a = 25^\circ\text{C}$)DIODE POWER DISSIPATION vs.
AMBIENT TEMPERATURETRANSISTOR POWER DISSIPATION vs.
AMBIENT TEMPERATURE